

TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

1SS154

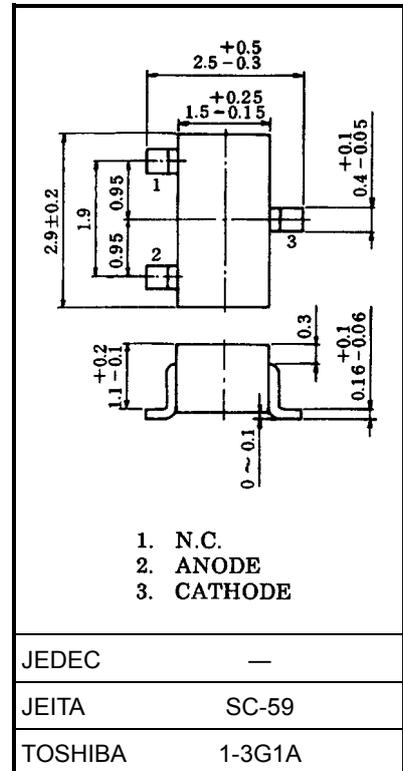
UHF~S Band Mixer/Detector Applications

Unit: mm

- Small package.

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|---------------------------|-----------|---------|------|
| Reverse voltage | V_R | 6 | V |
| Forward current | I_F | 30 | mA |
| Junction temperature | T_j | 125 | °C |
| Storage temperature range | T_{stg} | -30~125 | °C |



Electrical Characteristics (Ta = 25°C)

Weight: 0.012 g (typ.)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|-------------------|-----------|----------------------|-----|------|------|---------|
| Reverse voltage | V_R | $I_R = 10 \mu A$ | 6 | — | — | V |
| Reverse current | I_R | $V_R = 5 V$ | — | — | 0.5 | μA |
| Forward voltage | $V_F (1)$ | $I_F = 0.1 mA$ | — | — | 0.35 | V |
| Forward voltage | $V_F (2)$ | $I_F = 10 mA$ | — | 0.5 | — | V |
| Total capacitance | C_T | $V_R = 0, f = 1 MHz$ | — | 0.8 | — | pF |

Marking

